

# Single Schmitt-Trigger Inverter

# MC74VHC1G14, MC74VHC1GT14

The MC74VHC1G14 / MC74VHC1GT14 is a single Schmitt-Trigger Inverter in tiny footprint packages. The MC74VHC1G14 has CMOS-level input thresholds while the MC74VHC1GT14 has TTL-level input thresholds.

The internal circuit is composed of three stages, including a buffered output which provides high noise immunity and stable output.

The input structures provide protection when voltages up to 5.5~V are applied, regardless of the supply voltage. This allows the device to be used to interface 5~V circuits to 3~V circuits. Some output structures also provide protection when  $V_{\rm CC}=0~V$  and when the output voltage exceeds  $V_{\rm CC}$ . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

#### **Features**

- Designed for 2.0 V to 5.5 V V<sub>CC</sub> Operation
- 4.0 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, TSOP-5, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

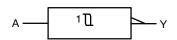
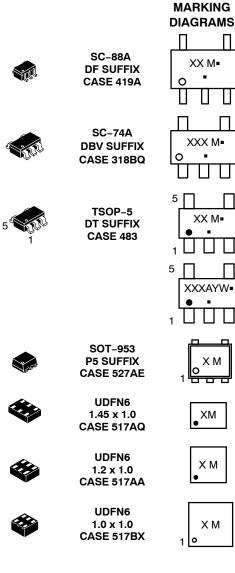


Figure 1. Logic Symbol



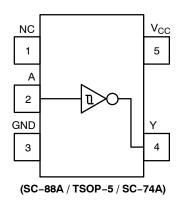
XX = Specific Device Code
M = Date Code\*
= Pb-Free Package

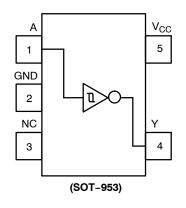
(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.





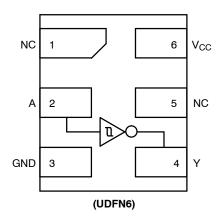


Figure 2. Pinout (Top View)

PIN ASSIGNMENT (SC-88A / TSOP-5 / SC-74A)

Pin	Function
1	NC
2	Α
3	GND
4	Υ
5	V <sub>CC</sub>

# PIN ASSIGNMENT (SOT-953)

Pin	Function
1	А
2	GND
3	NC
4	Y
5	V <sub>CC</sub>

#### PIN ASSIGNMENT (UDFN)

Pin	Function
1	NC
2	Α
3	GND
4	Y
5	NC
6	V <sub>CC</sub>

#### **FUNCTION TABLE**

A Input	Y Output		
L H	H		
	1		

#### **MAXIMUM RATINGS**

Symbol	Characteristics		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	Tri–S	High or Low State) tate Mode (Note 1) Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
l <sub>OUT</sub>	DC Output Source/Sink Current		±25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin		±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88A SC-74A SOT-953 UDFN6	377 320 254 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SC-74A SOT-953 UDFN6	332 390 491 812	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating Oxyg	en Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>		uman Body Model ged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
   HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
- 4. Tested to EIA/JESD78 Class II.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage  Active–Mode (High or Low State Tri–State Mode (Note: Power–Down Mode (V <sub>CC</sub> = 0 V	s) 0	V <sub>CC</sub> 5.5 5.5	V
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time $V_{CC}=2.0\\ V_{CC}=2.3\ \text{V to }2.7\\ V_{CC}=3.0\ \text{V to }3.6\\ V_{CC}=4.5\ \text{V to }5.5$	V 0 V 0	No Limit No Limit No Limit No Limit	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

5. Applicable to devices with outputs that may be tri-stated.

# DC ELECTRICAL CHARACTERISTICS (MC74VHC1G14)

		Test	v <sub>cc</sub>	1	Γ <sub>A</sub> = 25°	С	-40°C ≤ 7	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>T+</sub>	Positive Input Threshold Voltage		3.0 4.5 5.5	- - -	2.0 3.0 3.6	2.2 3.15 3.85	- - -	2.2 3.15 3.85	- - -	2.2 3.15 3.85	V
V <sub>T-</sub>	Negative Input Threshold Voltage		3.0 4.5 5.5	0.9 1.35 1.65	1.5 2.3 2.9	- - -	0.9 1.35 1.65	- - -	0.9 1.35 1.65	- - -	V
V <sub>H</sub>	Hysteresis Voltage		3.0 4.5 5.5	0.30 0.40 0.50	0.57 0.67 0.74	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	٧
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OH} &= -50  \mu A \\ I_{OH} &= -50  \mu A \\ I_{OH} &= -50  \mu A \\ I_{OH} &= -4 \text{ mA} \\ I_{OH} &= -8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 -	- - - -	1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{c} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 4 \text{ mA} \\ I_{OL} = 8 \text{ mA} \end{array}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - - -	0.1 0.1 0.1 0.44 0.44	- - - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0.0	_	_	1.0	-	10	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	-	40	μΑ

## DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT14)

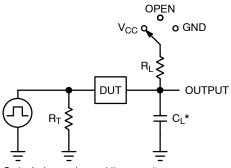
		Test	v <sub>cc</sub>	1	T <sub>A</sub> = 25°	С	-40°C ≤ 7	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	' <sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>T+</sub>	Positive Input Threshold Voltage		3.0 4.5 5.5		1.4 1.74 1.94	1.6 2.0 2.1	- - -	1.6 2.0 2.1	- - -	1.6 2.0 2.1	<b>V</b>
V <sub>T-</sub>	Negative Input Threshold Voltage		3.0 4.5 5.5	0.35 0.5 0.6	0.76 1.01 1.13	- - -	0.35 0.5 0.6	- - -	0.35 0.5 0.6	- - -	٧
V <sub>H</sub>	Hysteresis Voltage		3.0 4.5 5.5	0.30 0.40 0.50	0.64 0.73 0.81	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	V
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OH} &= -50  \mu A \\ I_{OH} &= -50  \mu A \\ I_{OH} &= -50  \mu A \\ I_{OH} &= -4 \text{ mA} \\ I_{OH} &= -8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –	- - - -	1.9 2.9 4.4 2.48 3.80	- - - - -	1.9 2.9 4.4 2.34 3.66	- - - - -	٧
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{c} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 4 \text{ mA} \\ I_{OL} = 8 \text{ mA} \end{array}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	_	1.0	-	10	-	10	μΑ
Icc	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	_	1.0	ı	20	-	40	μΑ
Ісст	Increase in Quiescent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	-	1.65	mA

#### **AC ELECTRICAL CHARACTERISTICS**

				Т	A = 25°	С	-40°C ≤ 1	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	7.0	12.8	-	15.0	-	17.0	ns
t <sub>PHL</sub>	A to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	8.5	16.3	-	18.5	-	20.5	
(1.15	(i igai co o ana i)	C <sub>L</sub> = 15 pF	4.5 to 5.5	-	4.0	8.6	-	10.0	-	11.5	
		C <sub>L</sub> = 50 pF		-	5.5	10.6	-	12.0	-	13.5	
C <sub>IN</sub>	Input Capacitance			-	4.0	10	-	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	ı	l	-	-	-	pF

		Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
$C_{PD}$	Power Dissipation Capacitance (Note 6)	8.0	pF

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



 $\begin{array}{c|cccc} t_{PLH} \ / \ t_{PHL} & Open & See \ AC \ Characteristics \ Table & X \\ \hline t_{PLZ} \ / \ t_{PZL} & V_{CC} & & 1 \ k \\ \hline t_{PHZ} \ / \ t_{PZH} & GND & & 1 \ k \\ \end{array}$ 

 $C_L$ , pF

 $R_L, \Omega$ 

X = Don't Care

Test

**Switch** 

**Position** 

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

Figure 3. Test Circuit

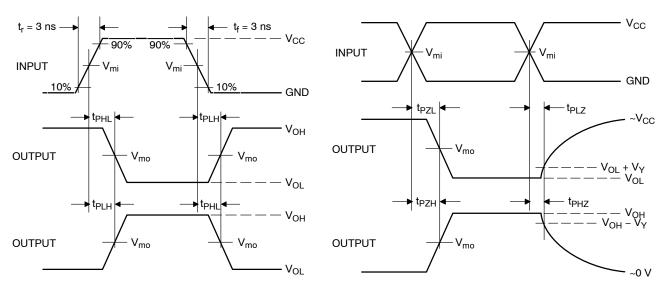


Figure 4. Switching Waveforms

		V <sub>m</sub>		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

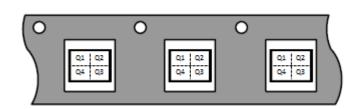
#### **ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G14DFT1G	SC-88A	VA	Q2	3000 / Tape & Reel
MC74VHC1G14DFT2G	SC-88A	VA	Q4	3000 / Tape & Reel
MC74VHC1G14DFT1G-Q*	SC-88A	VA	Q2	3000 / Tape & Reel
MC74VHC1G14DFT2G-Q*	SC-88A	VA	Q4	3000 / Tape & Reel
MC74VHC1GT14DFT1G	SC-88A	VC	Q2	3000 / Tape & Reel
MC74VHC1GT14DFT2G	SC-88A	VC	Q4	3000 / Tape & Reel
MC74VHC1GT14DFT1G-Q*	SC-88A	VC	Q2	3000 / Tape & Reel
MC74VHC1GT14DFT2G-Q*	SC-88A	VC	Q4	3000 / Tape & Reel
MC74VHC1G14DBVT1G	SC-74A	VA	Q4	3000 / Tape & Reel
MC74VHC1G14DBVT1G-Q*	SC-74A	VA	Q4	3000 / Tape & Reel
MC74VHC1GT14DBVT1G	SC-74A	VC	Q4	3000 / Tape & Reel
MC7VHC1G14DTT1G-Q* (Please contact <b>onsemi</b> )	TSOP-5	VA	Q4	3000 / Tape & Reel
MC74VHC1G14P5T5G	SOT-953	R	Q2	8000 / Tape & Reel
MC74VHC1GT14P5T5G (Please contact <b>onsemi</b> )	SOT-953	TBD	Q2	8000 / Tape & Reel
MC74VHC1G14MU1TCG (Please contact <b>onsemi</b> )	UDFN6, 1.45 x 1.0, 0.5P	TBD	Q4	3000 / Tape & Reel
MC74VHC1GT14MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	Q	Q4	3000 / Tape & Reel
MC74VHC1G14MU2TCG (Please contact <b>onsemi</b> )	UDFN6, 1.2 x 1.0, 0.4P	Р	Q4	3000 / Tape & Reel
MC74VHC1GT14MU2TCG	UDFN6, 1.2 x 1.0, 0.4P	М	Q4	3000 / Tape & Reel
MC74VHC1G14MU3TCG (Please contact <b>onsemi</b> )	UDFN6, 1.0 x 1.0, 0.35	TBD	Q4	3000 / Tape & Reel
MC74VHC1GT14MU3TCG	UDFN6, 1.0 x 1.0, 0.35	М	Q4	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## Pin 1 Orientation in Tape and Reel

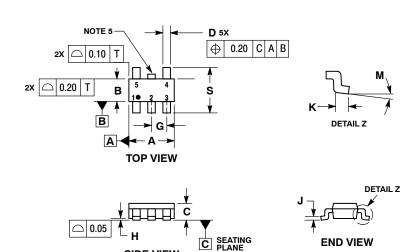
#### Direction of Feed



<sup>\*-</sup>Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

#### **PACKAGE DIMENSIONS**

#### TSOP-5 **CASE 483** ISSUE N



**SIDE VIEW** 

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

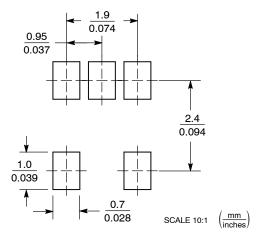
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.

  5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS			
DIM	MIN MAX			
Α	2.85	3.15		
В	1.35	1.65		
С	0.90	1.10		
D	0.25	0.50		
G	0.95 BSC			
Н	0.01	0.10		
J	0.10	0.26		
K	0.20	0.60		
М	0 °	10°		
S	2.50	3.00		

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



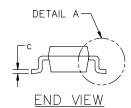


#### SC-74A-5 3.00x1.50x0.95, 0.95P CASE 318BQ ISSUE C

**DATE 26 FEB 2024** 

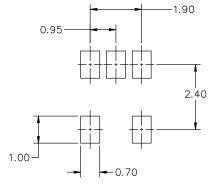
#### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.



DIM	MILENNE PERCO		
MIU	MIN.	NOM.	MAX.
Α	0.90	1.00	1.10
A1	0.01	0.18	0.10
A2	(	0.95 REF	
Ь	0.25	0.37	0.50
C	0.10	0.18	0.26
D	2.85	3.00	3.15
E	:	2.75 BSC	;
E1	1.35	1.50	1.65
е	(	0.95 BSC	;
L	0.20	0.40	0.60
L1	0.62 REF.		
L2	0.25 BSC		
Θ	0,	5°	10°

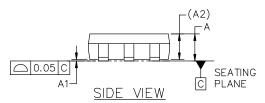
**MILLIMETERS** 

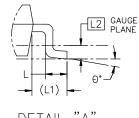


#### RECOMMENDED MOUNTING FOOTPRINT\*

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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DETAIL "A" SCALE 2:1

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

DESCRIPTION:	SC-74A-5 3.00x1.50x0.95,	0.95P	PAGE 1 OF 1
DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	

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#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

**DATE 11 APR 2023** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

	MILLIMETERS		
DIM			
	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3	0.20 REF		
b	0.10	0.20	0.30
С	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2,20
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.10	0.15	0.30

- 419A-01 DBSDLETE, NEW STANDARD 419A-02

	A3
40	0.50

5X b

◆ 0.2 M B M

#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

5. COLLECTOR

#### **GENERIC MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	<ol><li>EMITTER</li></ol>	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	<ol><li>SOURCE 1</li></ol>	3. CATHODE 2
4. COLLECTOR	<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE 2</li></ol>	4. GATE 1	4. CATHODE 3
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE 1</li></ol>	5. GATE 2	5. CATHODE 4
0T) (1 F 0:	OT) (1 E 7:	OT)// F 0:	STYLE 9:	Note: Disease refer to detect and for
STYLE 6:	STYLE 7:	STYLE 8:		Note: Please refer to datasheet for
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	style callout. If style type is not called
2. BASE 2	<ol><li>EMITTER</li></ol>	2. COLLECTOR	2. CATHODE	, ,,
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	out in the datasheet refer to the device
4. COLLECTOR	<ol><li>COLLECTOR</li></ol>	4. BASE	4. ANODE	datachast ningut or nin assignment
<ol><li>COLLECTOR 2/BASE 1</li></ol>	<ol><li>COLLECTOR</li></ol>	5. EMITTER	5. ANODE	datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from the Document Reported versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-88A (SC-70-5/SOT-35	3)	PAGE 1 OF 1

5. EMITTER

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5. COLLECTOR 2/BASE 1

△ aaa C

## UDFN6, 1.20x1.00x0.50, 0.40P CASE 517AA ISSUE E

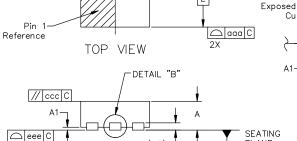
**DATE 09 MAY 2025** 

#### NOTES:

- DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018. 1
- CONTROLLING DIMENSION: MILLIMETERS.

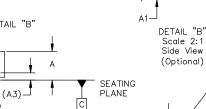
Mold Compound

- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL.
- COPLANARITY APPLIES TO TH EXPOSED PAD AS WELL AS THE TERMINALS.



SIDE VIEW

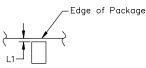
D



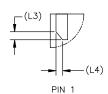
В

Ε

DETAIL "A"

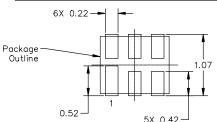


DETAIL "A" Scale 2:1 Bottom View (Optional)



Chamfer Dimension

MILLIMETERS			
DIM	MIN	NOM	MAX
А	0.45	0.50	0.55
Α1	0.00		0.05
А3	(	D.127 REF	
Ф	0.15	0.20	0.25
D		1.20 BSC	
Е		1.00 BSC	
е		0.40 BSC	
L	0.30	0.35	0.40
L1	0.00		0.15
L2	0.40	0.45	0.50
L3	0.14 REF		
L4	0.116 REF		
TOLER	ANCE FO	RM & PO	SITION
aaa	0.10		
bbb		0.10	
ССС	0.10		
ddd		0.05	
eee		0.08	



RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

L2	ЦΨ		5X L
†		πГ	I
	6	4 e	
6X b			
dad C B	MOTTC	VIEW	

# **GENERIC MARKING DIAGRAM\* XXM**

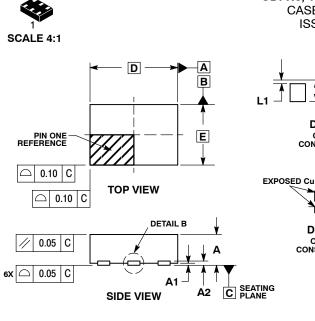
XX = Specific Device Code = Date Code М

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON22068D	Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6, 1.20x1.00x0.50, 0.4	40P	PAGE 1 OF 1

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е

6X L

6X b

Ф

0.10 | C | A | B

0.05 C NOTE 3

#### UDFN6, 1.45x1.0, 0.5P CASE 517AQ **ISSUE O**

**DETAIL A** OPTIONAL CONSTRUCTIONS

**DETAIL B** OPTIONAL CONSTRUCTIONS

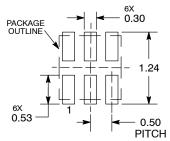
MOLD CMPD

**DATE 15 MAY 2008** 

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.45	0.55		
A1	0.00	0.05		
A2	0.07	REF		
b	0.20 0.30			
D	1.45 BSC			
Е	1.00 BSC			
е	0.50 BSC			
Ĺ	0.30	0.40		
L1		0.15		

#### **MOUNTING FOOTPRINT**



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 



Χ = Specific Device Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	UDFN6, 1.45x1.0, 0.5P		PAGE 1 OF 1

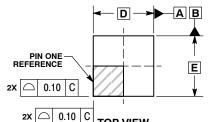
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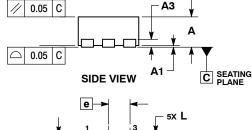


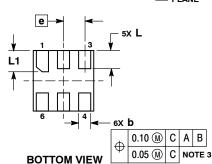
UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

**DATE 18 MAY 2011** 



**TOP VIEW** 



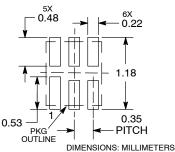


#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. PACKAGE DIMENSIONS EXCLUSIVE OF
- BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
А3	0.13 REF		
q	0.12	0.22	
D	1.00 BSC		
Е	1.00 BSC		
е	0.35 BSC		
Г	0.25	0.35	
L1	0.30	0.40	

#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **GENERIC MARKING DIAGRAM\***



X = Specific Device Code

M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	UDFN6, 1x1, 0.35P		PAGE 1 OF 1

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MILLIMFTERS

 $N\square M$ 

0.37

0.15

0.12

1.00

0.80

0.35 BSC

1.00

MIN

0.34

0.10

0.07

0.95

0.75

0.95





#### SOT-953 1.00x0.80x0.37, 0.35P CASE 527AE **ISSUE F**

**DATE 17 JAN 2024** 

MAX

0.40

0.20

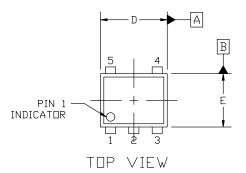
0.17

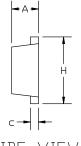
1.05

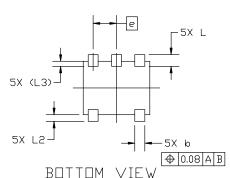
0.85

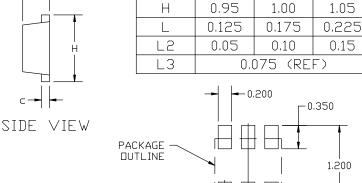
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.









0.350

DIM

Α

b

C

 $\mathbb{D}$ 

E

9 Н

# RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



= Specific Device Code

= Month Code

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DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0.35P		PAGE 1 OF 1

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